#### ATTORNEY/DOCKET No:

## DECLARATION FOR PATENT APPLICATION AND APPOINTMENT OF ATTORNEY

As a below named inventor, I hereby declare that my residence, post office address and oitizenship are as stated below next to my name; I believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is cought on the invention (Design, if applicable) entitled.

THERMALLY ENHANCED SEMICONDUCTOR BUILD-UP PACKAGE

SEND CORRESPONDENCE TO:

☐ is attached hereto; or ☐ was filed on:

as U.S. Application Number or PCT International Application Number;

and (if applicable) was amended on:

hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment(s) referred to above. I nekrowledge the duty to disclosion in formation which is material to patentiability and efficient in Title 37, Cache of Federal Regulations, § 1.56, I hereby claim foreign priority benefits under Title 33, United States Cache § 1/9 of any foreign application(s) for patent or inventor's certificate lated belowed have also identified below my foreign application for partent or inventor's certificate lated below do have also intentified below my foreign application for partent or inventor's certificate having a filline date before that of the amplication on the intentive is claimed.

PRIOR FOREIGN APPLICATION(S)							
Number	Country	Day/Month/Year Filed	Yes	No			
di R <sub>I</sub>							
n n	☐ Additional Priority Application(s) Listed on Following Page(s)						
I HEREBY CLAIM THE BENEFIT UNDER TITLE 35 U.S. CODE § 119(E) OF ANY U.S. PROVISIONAL APPLICATIONS LISTED BELOW.							
Applic	ation Number	Day/Month/Year Filed	Day/Month/Year Filed				
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0	Additional Provisional Application(s) Lis	ted on Following Page(s)					
n. I hereby claim the benefit under 7	itle 35. United States Code. \$120 of any United S						

Interby claim the benefit under Title 33, United States Code, §120 of any United States application(s) or PCT international application(s) designating The Gifted States of Americal Isted below and, insofar as the subject matter of each of the claims of this application is not disclosed individuoes prior application(s) in the manner provided by the first paragraph of Title 33, United States Code, §112, 1 acknowledge the duty to disclose information which is material to patentability as edigined in Title 37, Code of Federal Regulations, §1.56 which became available between the filing date of the prior applications) and the national or PCT international filing date of this application:

Application Number	Filing Date	Status - Patented, Pending or Abandoned

☐ Additional US/PCT Priority Application(s) listed on Following Page(s)

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made with missable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: I (We) hereby appoint as my (our) attorneys, with full powers of substitution and revocation, to prosecute this application and transact all business in the Patent and Trademark Office connected therewith:

### Bruce H. Troxell. Reg. No. 26,592

I (we) authorize my (our) attorneys to accept and follow instructions from <u>Advanced semiconductor Engineering</u>, Inc. regarding any matter related to the preparation, examination, grant and maintenance of this application, any continuation, continuation-in-part or divisional based thereon, and any patent resulting thereform, until I (ye) or my (our) assigns withdraw this authorization in writing.

TELEPHONE CALLS TO:

FALLS CHURCH, V	
FULL NAME OF FIRST OR SOLE INVENTOR In-De Ou	CITIZENSHIP REPUBLIC OF CHINA
RESIDENCE ADDRESS  No. 46, Lane 7, Shingjung 1st Rd., Lingya Cl Kaohsiung, Taiwan R.O.C.	POST OFFICE ADDRESS IS THE SAME AS RESIDENCE ADDRESS UNLESS OTHERWISE SHOWN BELOW
DATE January 16, 2002	SIGNATURE Ou Un De

BRUCE H. TROXELL

### ATTORNEY/DOCKET No:

# CONTINUATION OF DECLARATION FOR PATENT APPLICATION AND APPOINTMENT OF ATTORNEY

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PRIOR PROVISIONAL APPLICATIONS 35 U.S. CODE § 119(E)								
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Full Name of Joint Inventor Yi-Chuan I	Ding		Citizenship	REPUBL	IC OF CHINA			
Residence Address No. 2, Wenchiang Rd., Tzuoying Chiu, Kaohsiung, Taiwan R.O.C.		Post Office Address Is the Same as Residence Address Unless Otherwise Shown below						
Date January 16, 2002			Signature V' Chan (1)					
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Full Name of Joint Inventor Kun-Ching Chen			Citizenship REPUBLIC OF CHINA					
Residence Address No. 48, Lane 64, Sec. 2, Minchiuan Rd., Jung Chiu, Tainan, Taiwan R.O.C.		Post Office Address Is the Same as Residence Address Unless Otherwise Shown below						
Date January 16, 2002			Signature Chen Kum Ching					
Full Name of Joint Inventor	1000		Citizenship		77			
Residence Address		Post Office Address Is the Same as Residence Address Unless						
			Otherwise Sh	own below	,	0 0111000		
Date			Signature					
			Signature					
Full Name of Joint Inventor	-		Citizenship				$\neg$	
Residence Address			Post Office Address Is the Same as Residence Address Unless					
			Otherwise Shown below					

Signature

Date